

Table 1: Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	20	A
V_{DRM}/V_{RRM}	600 and 700	V
$I_{GT(Q_1)}(max)$	35 and 50	mA

Table 2: Order Codes

Part Numbers	Marking
BTA20-600BWRG	BTA20-600BW
BTA20-600CWRG	BTA20-600CW
BTA20-700BWRG	BTA20-700BW
BTA20-700CWRG	BTA20-700CW

DESCRIPTION

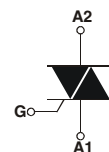
The **BTA20 BW/CW** triac family are high performance glass passivated chips technology.

The snubberless concept offer suppression of RC network and it is suitable for application such as phase control and static switching on inductive or resistive load.

Thanks to their clip assembly technique, they provide a superior performance in surge current handling capabilities.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500V_{RMS}) complying with UL standards (File ref.: E81734).

TO-220AB Insulated


Table 3: Absolute Maximum Ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)		$T_c = 70^\circ C$	20	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = $25^\circ C$)	F = 50 Hz	t = 10 ms	210	A
		F = 60 Hz	t = 8.3 ms	200	
I^2t	I^2t Value for fusing	$t_p = 10$ ms		200	A ² s
di/dt	Critical rate of rise of on-state current $I_G = 500$ mA $di_G/dt = 1$ A/ μ s	Repetitive F = 50 Hz	$T_j = 125^\circ C$	20	A/ μ s
		Non repetitive		100	
V_{DSM}/V_{RSM}	Non repetitive peak off-state voltage	$t_p = 10$ ms	$T_j = 25^\circ C$	$V_{DSM}/V_{RSM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20$ μ s	$T_j = 125^\circ C$	4	A
V_{GM}	Peak positive gate voltage	$t_p = 20$ μ s		16	V
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ C$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	$^\circ C$

Tables 4: Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test Conditions	Quadrant		BTA20		Unit
				BW	CW	
$I_{GT} (1)$	$V_D = 12\text{ V}$ $R_L = 33\ \Omega$	ALL	MIN.	2	1	mA
			MAX.	50	35	
V_{GT}		ALL	MAX.	1.5		V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$ $T_j = 125^\circ\text{C}$	ALL	MIN.	0.2		V
$I_H (2)$	$I_T = 500\text{ mA}$ gate open		MAX.	75	50	mA
I_L	$I_G = 1.2\ I_{GT}$	I - III	TYP.	50	-	mA
		II		90	-	
		I - II - III	MAX.	-	80	
$dV/dt (2)$	$V_D = 67\ \%V_{DRM}$ gate open	$T_j = 125^\circ\text{C}$	TYP.	750	500	V/ μs
			MIN.	500	250	
$(dV/dt)_c (2)$	$(dI/dt)_c = 20\text{ A/ms}$	$T_j = 125^\circ\text{C}$	TYP.	36	22	V/ μs
			MIN.	18	11	

Table 5: Static Characteristics

Symbol	Test Conditions			Value	Unit
$V_{TM} (2)$	$I_{TM} = 28\text{ A}$ $t_p = 380\ \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.70	V
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	MAX.	10	μA
		$T_j = 125^\circ\text{C}$		3	mA

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1.

Table 6: Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	2.1	$^\circ\text{C/W}$
$R_{th(j-c)}$	Junction to case (DC)	2.8	
$R_{th(j-a)}$	Junction to ambient	60	$^\circ\text{C/W}$

Figure 1: Maximum power dissipation versus RMS on-state current (full cycle)

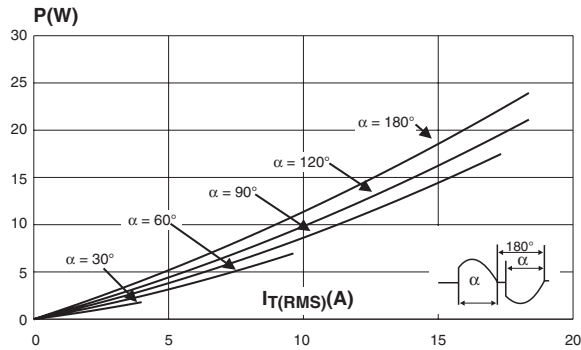


Figure 3: RMS on-state current versus case temperature (full cycle)

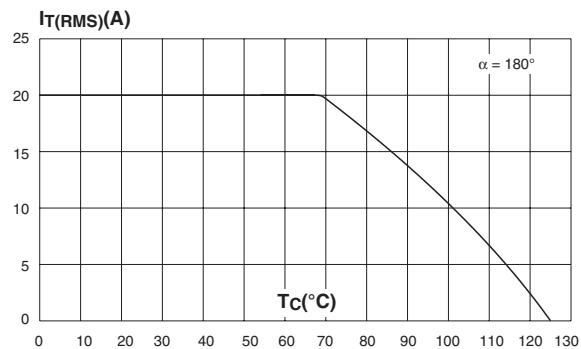


Figure 5: On-state characteristics (maximum values)

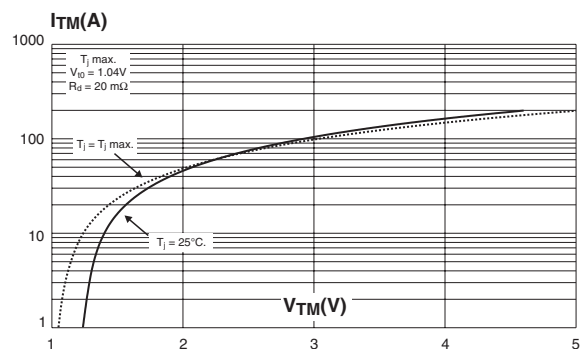


Figure 2: Correlation between maximum RMS power dissipation and maximum allowable temperatures (Tamb and Tcase) for different thermal resistances heatsink + contact

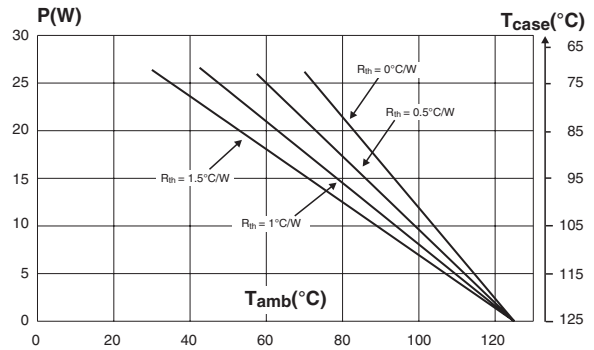


Figure 4: Relative variation of thermal impedance versus pulse duration

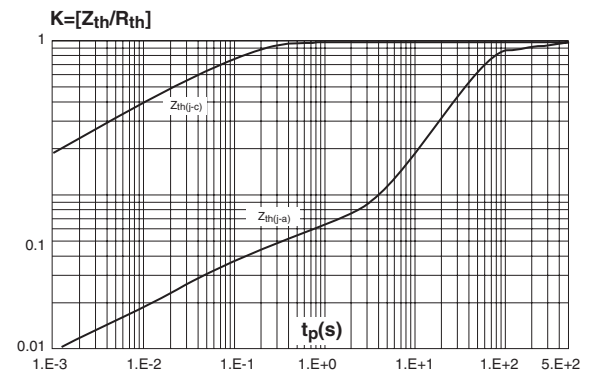


Figure 6: Non repetitive surge peak on-state current versus number of cycles

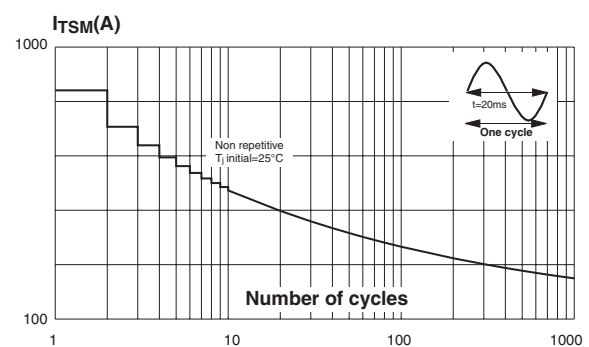


Figure 7: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms and corresponding value of I^2t

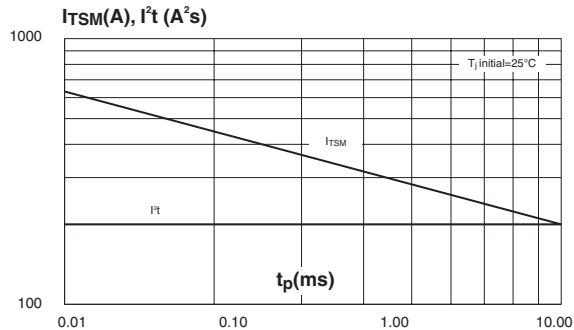


Figure 8: Relative variation of gate trigger current and holding current versus junction temperature

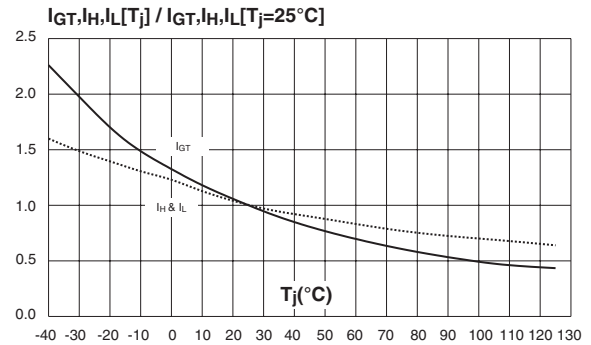


Figure 9: Ordering Information Scheme

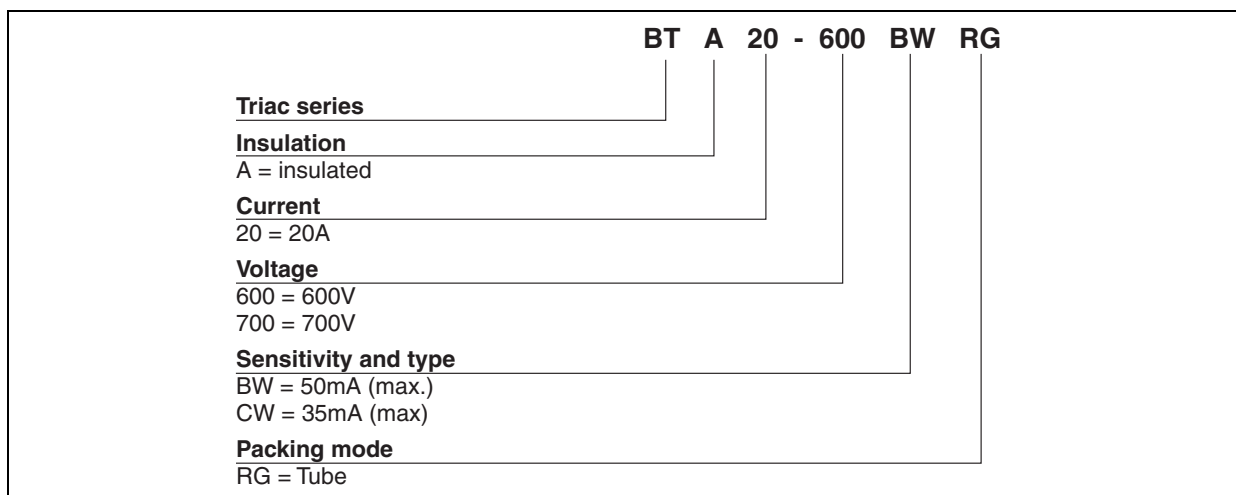


Table 7: Product Selector

Part Numbers	Voltage (xxx)		Sensitivity	Type	Package
	600 V	700 V			
BTA20-xxxBWRG	X	X	50 mA	Snubberless	TO-220AB Ins.
BTA20-xxxCWRG	X	X	35 mA		